2SC5909

Silicon NPN triple diffusion mesa type

For horizontal deflection output

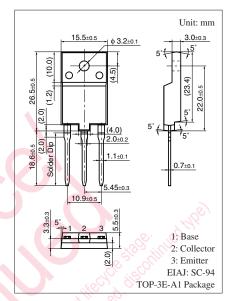
■ Features

- High breakdown voltage: $V_{CBO} \ge 1500 \text{ V}$
- High-speed switching: t_f < 200 ns
- Wide safe operation area

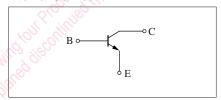
■ Absolute Maximum Ratings $T_C = 25$ °C

Parameter		Symbol	Rating	Unit	
Collector-base voltage (Emitter open)		V_{CBO}	1 500	V	
Collector-emitter voltage (E-B short)		V _{CES}	1 500	V	
Collector-emitter voltage (Base open)		V _{CEO}	600	V	
Emitter-base voltage (Collector open)		V_{EBO}	7	V	
Base current		I_B	5	A	
Collector current		I _C	15	A	
Peak collector current *		I _{CP}	25	A	
Collector power dissipation		P_{C}	50	W	
Ta	= 25°C		3		
Junction temperature		$T_{\rm j}$	150	°C	
Storage temperature		T_{stg}	-55 to +150	°C	

Note) *: Non-repetitive peak collector current



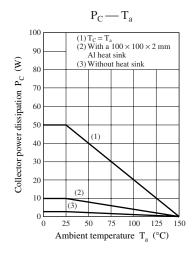
Internal Connection

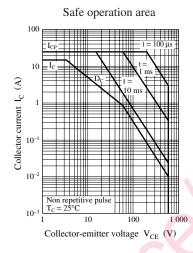


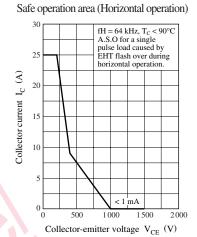
■ Electrical Characteristics $T_C = 25$ ° $C \pm 3$ °C

Parameter	Symbol	Conditions	Min	Тур	Max	Unit
Collector-base cutoff current (Emitter open)	I_{CBO}	$V_{CB} = 1000 \text{ V}, I_E = 0$			50	μΑ
	"Ligh" of	$V_{CB} = 1500 \text{ V}, I_E = 0$			1	mA
Emitter-base cutoff current (Collector open)	I_{EBO}	$V_{EB} = 7 \text{ V}, I_{C} = 0$			50	μΑ
Forward current transfer ratio	h_{FE}	$V_{CE} = 5 \text{ V}, I_{C} = 7.5 \text{ A}$	5		10	_
Collector-emitter saturation voltage	V _{CE(sat)}	$I_C = 7.5 \text{ A}, I_B = 1.88 \text{ A}$			2.5	V
Base-emitter saturation voltage	V _{BE(sat)}	$I_C = 7.5 \text{ A}, I_B = 1.88 \text{ A}$			1.5	V
Transition frequency	f_T	$V_{CE} = 10 \text{ V}, I_{C} = 0.1 \text{ A}, f = 0.5 \text{ MHz}$		3		MHz
Storage time	t _{stg}	$I_C = 7.5 \text{ A}$, Resistance loaded			2.7	μs
Fall time	$t_{\rm f}$	$I_{B1} = 1.88 \text{ A}, I_{B2} = -3.75 \text{ A}$			0.2	μs

Note) Measuring methods are based on JAPANESE INDUSTRIAL STANDARD JIS C 7030 measuring methods for transistors.







2 SJD00307AED

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